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Novosibirsk 630090, Russian Federation
<http://grapheneconf.ru>

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The conference implements a national platform for discussion of scientific and practical achievements in the field of synthesis and application of graphene and related structures, identify current issues and prospects of research in this area. The conference will bring together nearly 150 leading experts from major research centers and universities of Russia and will be attended by foreign scientists.

The official conference language - Russian

SUGGESTED TOPICS:

- CVD-synthesis of graphene
- Diagnosis of graphene
- Graphene electronics
- Mechanical properties and applications
- Microelectromechanical systems
- Chemical derivatives of graphene: synthesis, structure, properties
- Electrochemical materials
- Optical properties
- Hybrid materials based on graphene

RELATED SEMINARS:

- Non-carbon 2D materials
- Related sp²-carbon materials
- Theoretical methods in the annex to graphene materials

KEY DATES

The deadline for registration and abstract submission	is April 15. 2017
Notification of inclusion in the program	- May 01. 2017
The deadline of registration fee payment	- July 01. 2017
Conference program	- August 01. 2017
Deadline for submission of papers to the Journal of structural chemistry	- September 30.2017

VENUE

Novosibirsk, Akademgorodok, Novosibirsk state university, aud. 3307.

ACCOMODATION OF PARTICIPANTS

Novosibirsk, Pirogova str., 1; Hotel "Golden Valley"

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